

Charge, heat, and spin transport

Gerrit Bauer



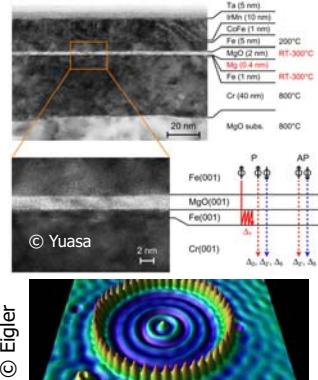
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Requirements for theory of magnetoelectronics

Metals and insulators:

Fermi/screening wave length $O(\text{\AA})$; disorder; sharp interfaces

- Size quantization effects on transport negligible (exception: MgO/Fe/Cr).
- Many-body effects negligible (exception: Kondo effect).
- Weak spin-orbit interaction.
- Quantum mechanics at the interfaces.



Overview first two lectures

1 Elementary transport theory

- Linear response theory of transport
- Scattering theory of transport
- Semiclassical transport
- Thermoelectricity and Onsager symmetry
- Collinear spin transport

G.D. Mahan, *Many-Particle Physics*, (Springer, 2000).
S. Doniach, E. H. Sondheimer, *Green's Functions for Solid State Physicists* (Imperial, 1998)

A. Brataas et al.,
Physics Reports
427, 157 (2006)

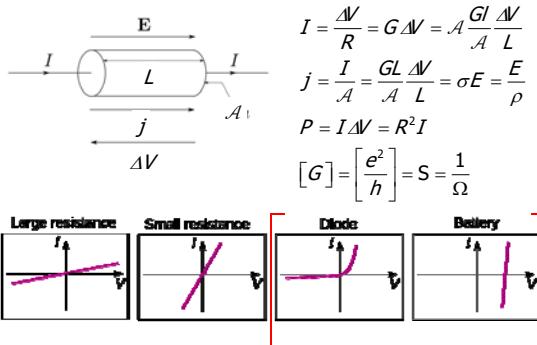
2 DC magnetoelectronic circuit theory

- Transport in non-collinear magnetization textures, non-collinear spin valves
- Spin transfer torque and spin mixing conductance
- Spiral/Kirchhoff Laws

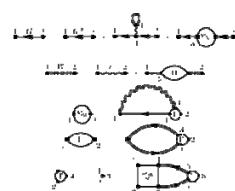
Y. Tserkovnyak et al., Rev. Mod. Phys., 77 1375 (2005).

Not: domain walls, tunnel junctions, (spin-orbit interaction)

Ohm's Law



Linear response of heat and mass transport: Fourier/Fick Laws



Perturbation theory of transport

Perturbation theory

Applied electric field \mathbf{E} generates current $\langle \mathbf{j} \rangle$ in a system H_0 :

$$H = H_0 + H' \text{ where } H' = -\mathbf{e} \cdot \mathbf{r} \cdot \mathbf{E} \quad \langle \varphi_i | \varphi_i \rangle = \epsilon_i | \varphi_i \rangle$$

$$|\psi_i\rangle = |\varphi_i\rangle + |\varphi_i'\rangle \text{ where } |\varphi_i'\rangle = \sum_{j \neq i} \frac{\langle \varphi_j | H' | \varphi_i \rangle}{\epsilon_i - \epsilon_j} | \varphi_j \rangle$$

$$\begin{aligned} \langle \mathbf{j} \rangle &= \sum_i f_i \langle \psi_i | \mathbf{j} | \psi_i \rangle = \sum_i f_i \left[\langle \varphi_i | \mathbf{j} | \varphi_i \rangle + \text{h.c.} \right] & f_i \text{ occupation number} \\ &= \sum_i f_i \sum_{i \neq j} \left[e \frac{\langle \varphi_i | \mathbf{j} | \varphi_j \rangle \langle \varphi_j | \mathbf{r} | \varphi_i \rangle}{\epsilon_i - \epsilon_j} + \text{h.c.} \right] \cdot \mathbf{E} = \sigma \cdot \mathbf{E} \end{aligned}$$

$$\langle \varphi_i | \mathbf{j} | \varphi_j \rangle = \frac{e\hbar}{2mr} (\varphi_i^* \nabla \varphi_j - \text{h.c.}) \quad \sigma \text{ conductance tensor}$$

But $\langle \varphi_j | \mathbf{r} | \varphi_i \rangle$ is problematic for large systems.

Kubo formula

$$H = \frac{1}{2m} [\mathbf{p} - e\mathbf{A}]^2 + U = \frac{\mathbf{p}^2}{2m} + U + \mathbf{j} \cdot \mathbf{A} + \frac{e\mathbf{A}^2}{2m}$$

$$\left(\nabla \cdot \mathbf{A} = 0; \quad \mathbf{E} = -\frac{\partial \mathbf{A}}{\partial t} \right) \quad \mathbf{A}(t) = \mathbf{A}_0 e^{-i\omega t} \rightarrow \mathbf{E} = i \frac{\mathbf{A}_0}{\omega}$$

$H' = \mathbf{j}(\mathbf{r}) \cdot \mathbf{A}(t)$ by time-dependent perturbation theory

$$(\sigma)_{ij}(\mathbf{r}, \mathbf{r}') = \lim_{\omega \rightarrow 0} \left\{ i \frac{ne^2}{m\omega} \delta_{ij} + \frac{1}{\hbar\omega\Omega} \int_0^\infty dt e^{i\omega t} \langle \Psi_0 | [j_i(\mathbf{r}, t), j_j(\mathbf{r}', 0)] | \Psi_0 \rangle \right\}$$

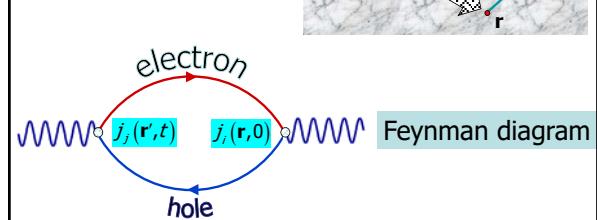
$|\Psi_0\rangle$ ground state wavefunction (no field)
 $j_i(\mathbf{r}, t)$ current operator in Heisenberg picture

$[a, b] = ab + ba$ commutator

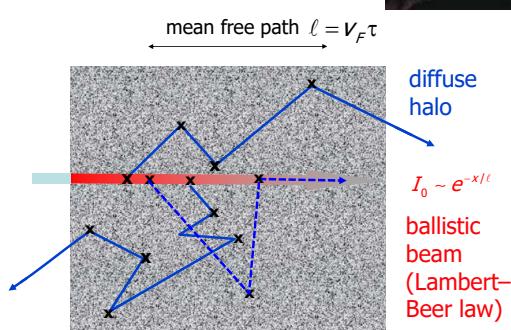
Fluctuation-dissipation theorem

Linear response (Kubo) formalism

$$\langle \mathbf{j}(\mathbf{r}) \rangle = \int_V d\mathbf{r}' \sigma(\mathbf{r}, \mathbf{r}') \cdot \mathbf{E}(\mathbf{r}')$$



Disorder



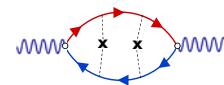
Impurity scattering (short-range)



ballistic: $\sigma = \infty$



Drude: $\sigma_0 = \frac{ne^2\tau}{m}$
 $\tau^{-1} \sim nV_x^2$



diffuse scattering (ladder)



interference (cross)
 $\Delta\sigma < 0$ weak localization

Scattering theory of transport

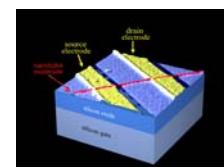
Josiah McElheny, 2006
The Last Scattering Surface



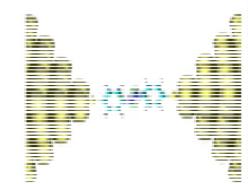
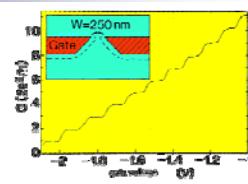
Nanostructures

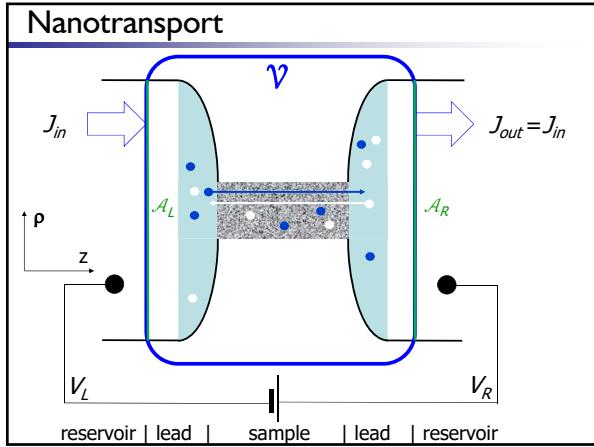


quantum point contacts



quantum wires





Fisher-Lee theory

Phys. Rev. B 23, 6851 (1981)

$$J_{out} = \int_{A_R} \mathbf{j}(\mathbf{p}, z) d\mathbf{p} = \int_{A_R} d\mathbf{p} \int_V d\mathbf{r}' \hat{\mathbf{z}} \cdot \boldsymbol{\sigma}(\mathbf{r}, \mathbf{r}') \cdot \mathbf{E}(\mathbf{r}')$$

$$e\mathbf{E}(\mathbf{r}) = \nabla \mu(\mathbf{r}) \quad \text{In the leads:} \quad \mathbf{E}(\mathbf{r}) = 0$$

Divergence theorem and current conservation ($\nabla \cdot \mathbf{j}(\mathbf{r}) = 0$):

$$\int_V d\mathbf{r}' \hat{\mathbf{z}} \cdot \boldsymbol{\sigma}(\mathbf{r}, \mathbf{r}') \cdot \mathbf{E}(\mathbf{r}') \cdot \nabla \mu(\mathbf{r}') = \int_{A_L} d\mathbf{p}' \hat{\mathbf{z}} \cdot \boldsymbol{\sigma}(\mathbf{r}, \mathbf{r}') \mu(\mathbf{r}')$$

$$eJ = (\mu_R - \mu_L) \int_{A_L} d\mathbf{p}' \int_{A_R} d\mathbf{p} (\boldsymbol{\sigma})_{zz}(\mathbf{r}, \mathbf{r}') = G \Delta \mu$$

independent of electric field distribution

Landauer-Büttiker formula

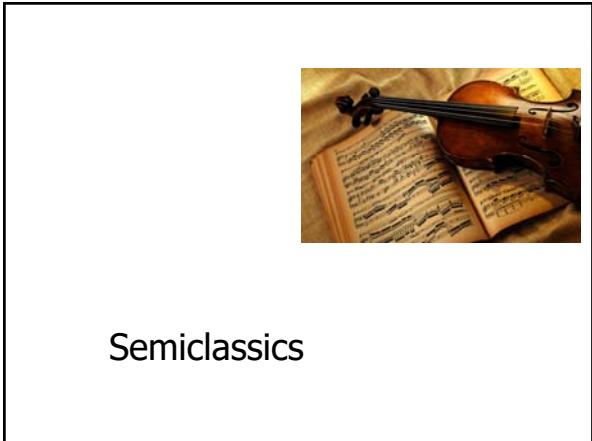
$$G = \int_{A_L} d\mathbf{p} \int_{A_R} d\mathbf{p}' (\boldsymbol{\sigma})_{zz}(\mathbf{r}, \mathbf{r}')$$

Expansion into eigenstates i, j of the leads at Fermi energy

$$G = \frac{e^2}{h} \sum_i^{k_F^{(R)} > 0, \mu} \sum_j^{k_F^{(L)} > 0, \mu} |t_{ij}|^2 = \frac{e^2}{h} \sum_j |t_{ij}|^2 = \frac{e^2}{h} \sum_j T_{ij}$$

t_{ij} transmission coefficient
(probability amplitude)

$T_{ij} = |t_{ij}|^2$ transmission probability



Interference and semiclassical approximation

Wigner representation:

$$\langle \mathbf{j}(\mathbf{r}) \rangle = \int_V d\mathbf{r}' \mathbf{G}(\mathbf{r}, \mathbf{r}') \cdot \mathbf{j}(\mathbf{r}', \mathbf{r}')$$

$$\mathbf{G}(\mathbf{r}, \mathbf{r}') \Rightarrow \mathbf{G}\left(\frac{\mathbf{r} + \mathbf{r}'}{2}, \mathbf{r} - \mathbf{r}'\right)$$

$$\mathbf{G}(\mathbf{R}, \mathbf{k}) = \int d(\mathbf{r} - \mathbf{r}') \mathbf{G}(\mathbf{R}, \mathbf{k}) e^{i\mathbf{k}(\mathbf{r} - \mathbf{r}')}$$

Semiclassical approximation holds for disordered metals:

$$\mathbf{j}(\mathbf{R}) = \sum_{\mathbf{k}} \mathbf{G}(\mathbf{R}, \mathbf{k}) \cdot \mathbf{j}_{\mathbf{k}} \rightarrow \sum_{\mathbf{k}} f_{\mathbf{k}}(\mathbf{R}) \cdot \mathbf{j}_{\mathbf{k}}$$

$$\mathbf{j}_{\mathbf{k}} = e\mathbf{v}_{\mathbf{k}} = \frac{e\partial\varepsilon_{\mathbf{k}}}{\partial\mathbf{k}} \rightarrow \frac{e\hbar}{m^*} \mathbf{k} \quad f_{\mathbf{k}}(\mathbf{R}) > 0$$

Distribution functions

$f_{\mathbf{k}}(\mathbf{R}, \delta t) = f_{\mathbf{k} + \frac{e\mathbf{E}_{\delta t}}{\hbar}}(\mathbf{R} - \mathbf{v}_{\mathbf{k}} \delta t)$ electron distribution function

$$\frac{df}{dt} = \left(\mathbf{v}_{\mathbf{k}} \cdot \frac{\partial}{\partial \mathbf{R}} + \frac{e\mathbf{E}}{\hbar} \cdot \frac{\partial}{\partial \mathbf{k}} \right) f_{\mathbf{k}}(\mathbf{R}) - \left(\frac{\partial f}{\partial t} \right)_{\text{scatt}} = 0 \quad \text{steady state Boltzmann equation}$$

$$f_{\mathbf{k}}(\mathbf{R}) \approx f_0(\varepsilon, \mathbf{R}) \Big|_{\varepsilon = \varepsilon_{\mathbf{k}}} + \frac{\partial f_0(\varepsilon, \mathbf{R})}{\partial \varepsilon} g_{\mathbf{k}}(\mathbf{R}) \quad \text{linearization}$$

$$f_0(\varepsilon, \mathbf{R}) = f_0^{(\alpha)}(\varepsilon, \mathbf{R}) \Big|_{\varepsilon = \varepsilon_{\mathbf{k}_0}} = (2\pi)^{-3} \int d\Omega_{\mathbf{k}} \frac{1}{e^{-(\varepsilon_{\mathbf{k}} - \mu(\mathbf{R}))/kT} - 1} \quad \text{Fermi-Dirac distribution}$$

$$\frac{\partial f_0(\varepsilon, \mathbf{R})}{\partial \varepsilon} \xrightarrow{kT \ll \mu} -\delta(\varepsilon - \mu(\mathbf{R})) \quad \text{Fermi energy}$$

$$g_{\mathbf{k}}(\mathbf{R}) \quad \text{deformation due to perturbation}$$

Diffusion approximation

$$\left(\frac{\partial f}{\partial t}\right)_{\text{scatt}} = -\frac{g_k(\mathbf{R})}{\tau_k} + \sum_{\mathbf{k}} W_{kk} g_k(\mathbf{R}) \rightarrow -\frac{g_k(\mathbf{R})}{\tau} + W \sum_{\mathbf{k}} g_k(\mathbf{R}) = 0$$

$\tau_k \approx \tau$ relaxation time approximation
 $W_{kk} \approx W$ (short range impurity scattering)

$$\mathbf{v}_k \cdot \left[\nabla_{\mathbf{R}} - e \mathbf{E} \frac{\partial}{\partial \epsilon} \right] f_0(\epsilon, \mathbf{R}) + \frac{\partial f_0(\epsilon, \mathbf{R})}{\partial \epsilon} \frac{g_k(\mathbf{R})}{\tau} = 0$$

$$g_k(\mathbf{R}) \approx -\tau \mathbf{v}_k \cdot [\nabla \mu(\mathbf{R}) - e \mathbf{E}]$$

$$g_k \rightarrow e \tau V_F E \cos \theta_k$$

$$\sigma \equiv \frac{e^2 \tau}{3V} \sum_{\mathbf{k}} V_k^2 \left(-\frac{\partial f_0}{\partial \epsilon_k} \right) \rightarrow \frac{n e^2 \tau}{m^*}$$

Diffusion in bulk 3D metal

Ohm's Law

$$\frac{\partial V(x)}{\partial x} = E = \rho j$$

$$\rho = \frac{m^*}{ne^2 \tau} \quad \text{resistivity}$$

$$R = \frac{\rho L}{A} \quad \text{resistance}$$

Current conservation

$$\frac{\partial}{\partial x} \frac{\partial \mu(x)}{\partial x} = 0 \rightarrow \frac{eE}{\rho} = \text{const.}$$

Interfaces



Interfaces

$$I = G_{LB}^I (V_1 - V_2)$$

$$G_{LB}^I = \frac{e^2}{h} \sum_j |t_j|^2 = \frac{e^2}{h} \sum_{k=1}^N T_k$$

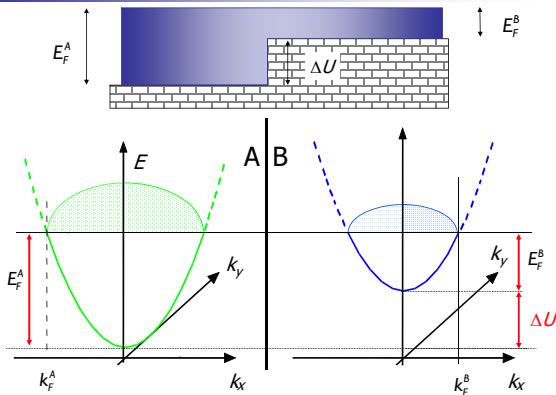
Landauer-Büttiker formula

Ballistic point contact:

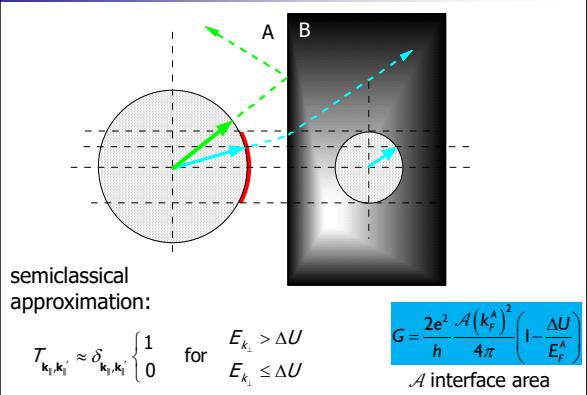
$$G_{LB} \xrightarrow{2 \rightarrow 1} G_{\text{Sharvin}} = \frac{2e^2}{h} \sum_j \delta_{ij} = \frac{2e^2}{h} \frac{\mathcal{A}}{(2\pi)^2} \int d\mathbf{k}_{||} = \frac{2e^2}{h} \frac{\mathcal{A} k_F^2}{4\pi}$$

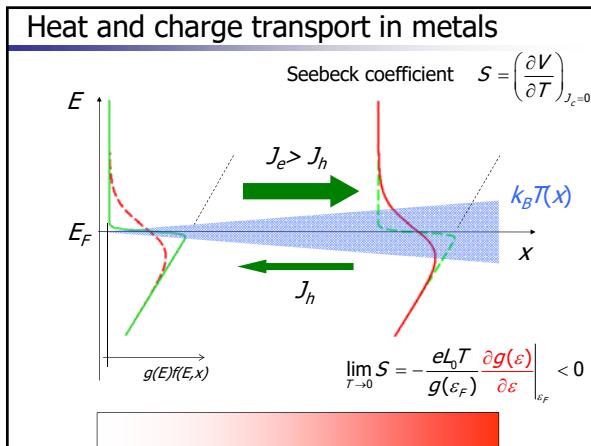
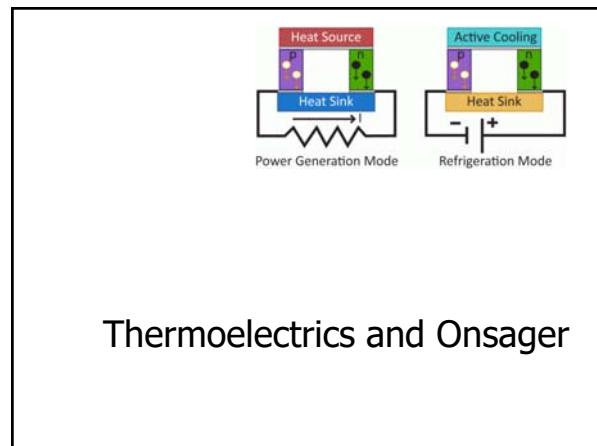
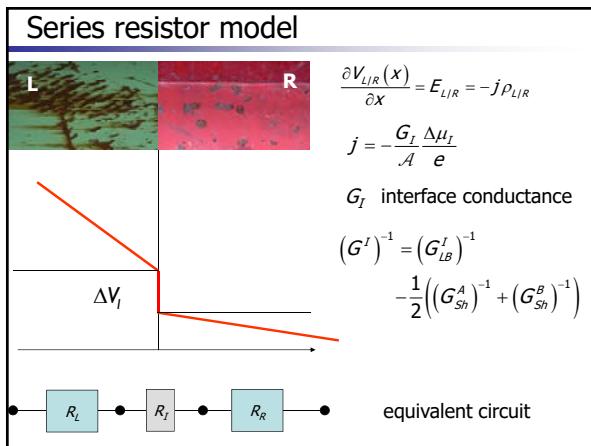
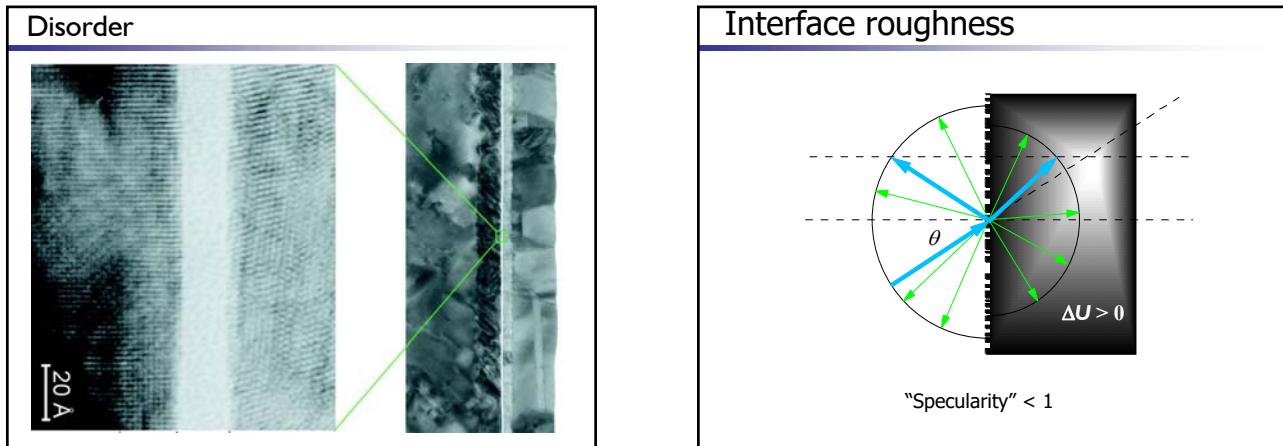
Sharvin conductance

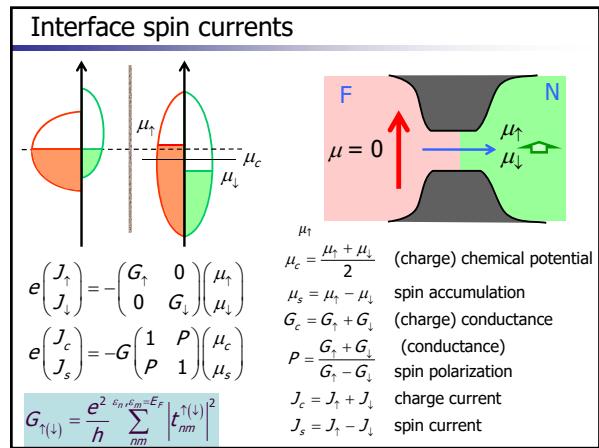
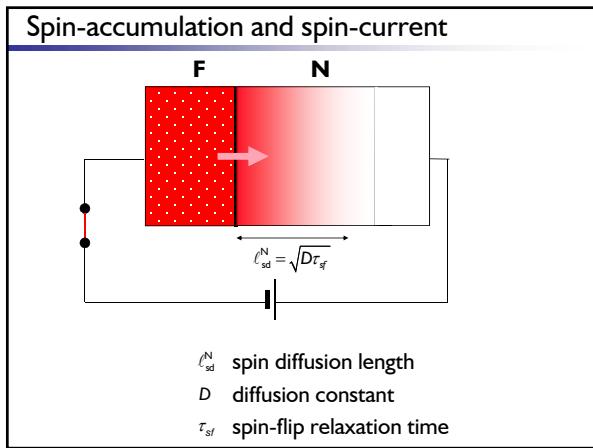
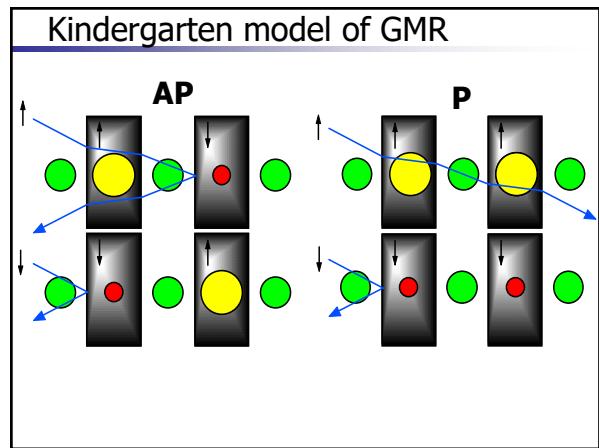
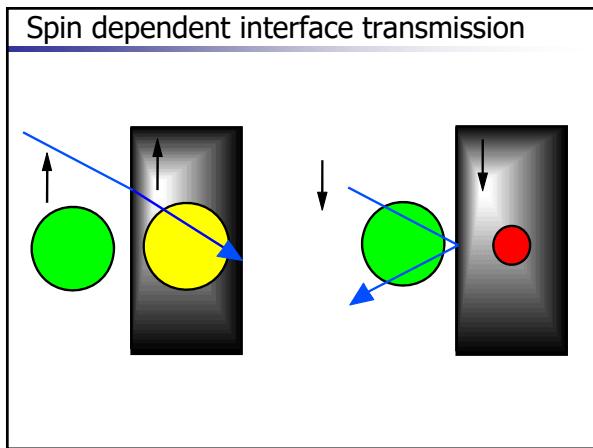
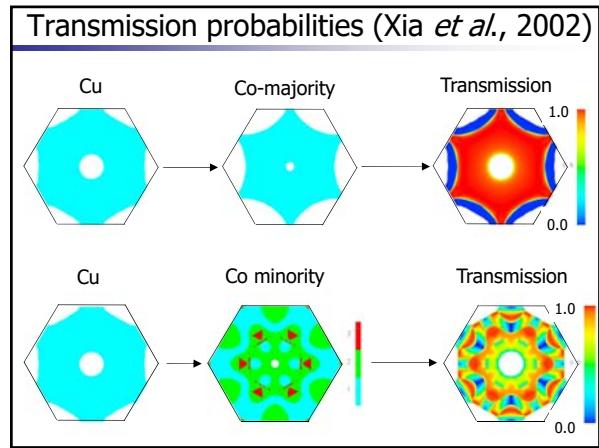
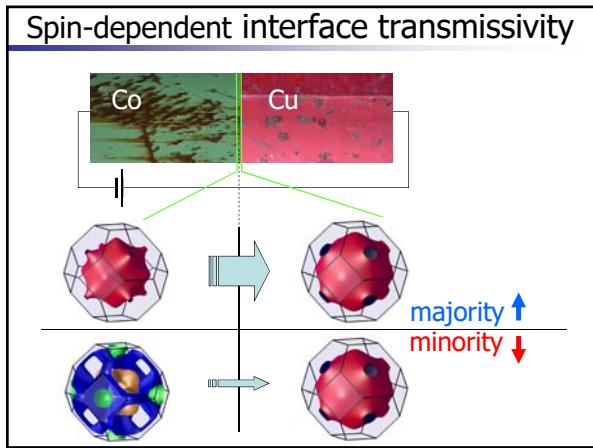
Metallic interface



Specular metallic interface







Spin diffusion in bulk metal (Valet-Fert)

Ohm's Law $j_s = -\sigma \frac{\partial \mu_s(x)}{\partial x}, \quad s = \{\uparrow, \downarrow\}$

spin relaxation $\frac{\partial(j_\uparrow - j_\downarrow)}{\partial x} = \frac{e(n_\uparrow - n_\downarrow)}{\tau_{sf}}$

spin-flip diffusion $\frac{\partial^2(\mu_\uparrow - \mu_\downarrow)(x)}{\partial x^2} = \frac{(\mu_\uparrow - \mu_\downarrow)(x)}{\ell_{sd}^2}$

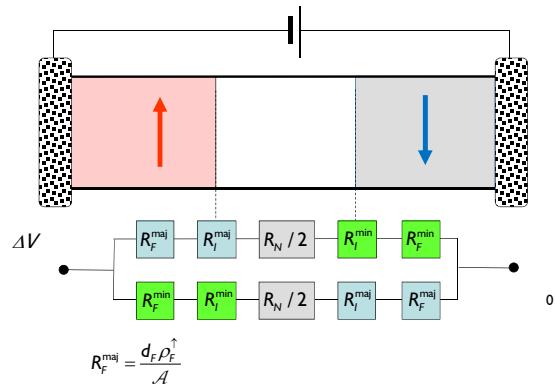
$$\ell_{sd} = \sqrt{D\tau_{sf}}$$

spin diffusion length

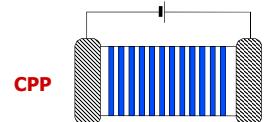
$$D = \frac{1}{3} V_F^2 \tau$$

averaged diffusion constant

Two-channel series resistor model



Two-channel series resistor model



$$\mathcal{A}R_s^T = N_{bl} \left(\rho_s^{(F)} d_F + \frac{\rho_s^{(N)} d_N}{2} + 2\mathcal{A}R_{\uparrow}^{(F|N)} \right)$$

\mathcal{A} cross section of sample
 N_{bl} number of bilayers
 $\rho_\uparrow^{(F)}$ spin-up resistivity of F
 $R_{\uparrow}^{(F|N)}$ spin-up interface resistance

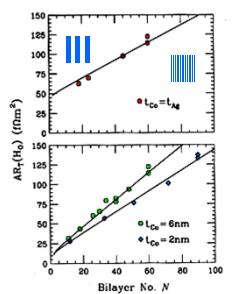
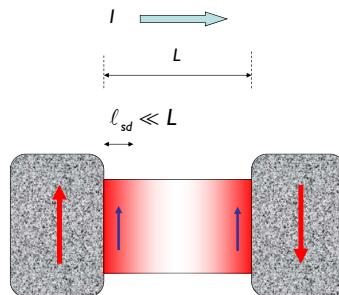


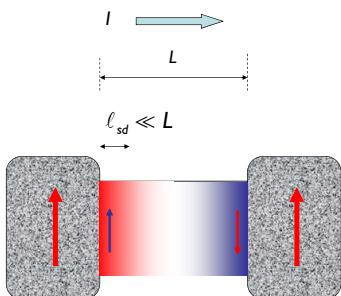
Fig. 2. $\Delta R_s(H_0)$ versus bilayer number N for three different sets of Co/Ag multilayers, all with fixed total thickness $t = 720$ nm. The curves shown are fits to the two-channel model!

MSU group in the 90's

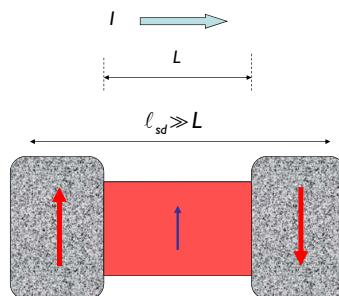
F|N|F spin valves



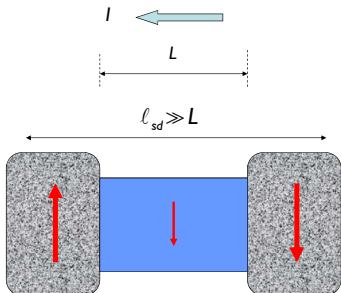
F|N|F spin valves



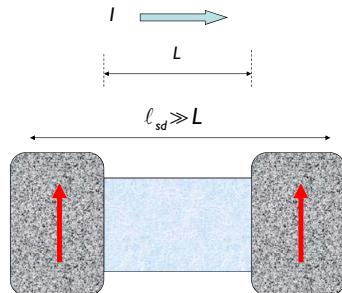
F|N|F spin valves



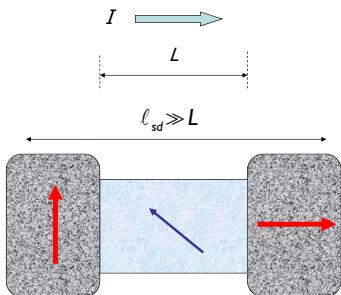
F|N|F spin valves



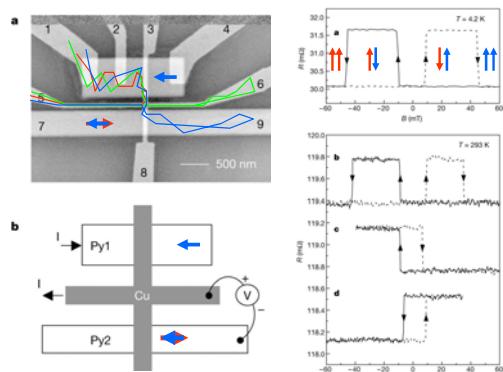
F|N|F spin valves



F|N|F spin valves: non-collinear



Jedema et al. (2001)



Tombros et al. (2007)

